Vishay Semiconductors

High Performance Schottky Rectifier, 20 A



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PRIMARY CHARACTERISTICS							
I _{F(AV)} 20 A							
V _R	15 V						
V _F at I _F	See Electrical table						
I _{RM} max.	600 mA at 100 °C						
T _J max.	125 °C						
E _{AS}	10 mJ						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and qualified according to JEDEC[®]-JESD47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UN							
I _{F(AV)}	Rectangular waveform	20	А				
V _{RRM}		15	V				
I _{FSM}	t _p = 5 μs sine	700	А				
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V				
TJ	Range	-55 to +125	°C				

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-STPS20L15D-M3 UNITS							
Maximum DC reverse voltage	V _R	15	V				
Maximum working peak reverse voltage	V _{RWM}	15	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle, $T_C = 85 \ ^\circ C$, r	20	А					
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	700	A				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 m⊦	10	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxin	2	А					

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 1
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VS-STPS20L15D-M3



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS		
Forward voltage drop See fig. 1		19 A	T.I = 25 °C	-	0.41	v	
	V _{FM} ⁽¹⁾	40 A	1j=25 0	-	0.52		
	V FM (*)	19 A	– T _J = 125 °C	0.25	0.33		
		40 A	$I_{\rm J} = 125$ C	0.37	0.50		
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	-	10	mA	
See fig. 2	IRM \''	T _J = 100 °C	V _R = haleu V _R	-	600	ША	
Threshold voltage	V _{F(TO)}	(TO) T T T		82	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum	- TJ maximum 7.6		.6	mΩ	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rat	-	2000	pF		
Typical series inductance	L _S	Measured lead to lead 5	8	-	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		-55 to +125	°C		
Maximum storage temperature range	T _{Stg}		-55 to +150			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40	1		
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque		Non-lubricated threads	6 (5)	kgf · cm		
Mounting torque maximum		Non-Iudricated triteads	12 (10)	$(lbf \cdot in)$		
Marking device		Case style TO-220AC 2L	STPS2	0L15D		



VS-STPS20L15D-M3

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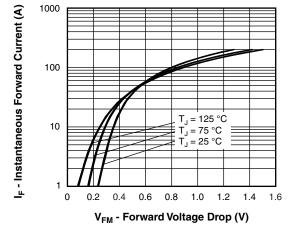


Fig. 1 - Maximum Forward Voltage Drop Characteristics

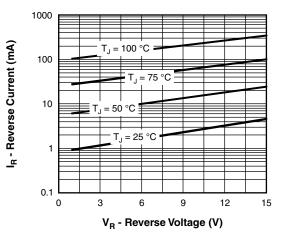


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

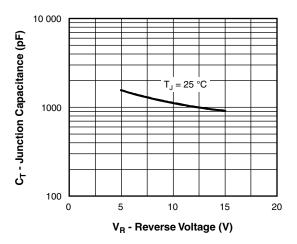


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

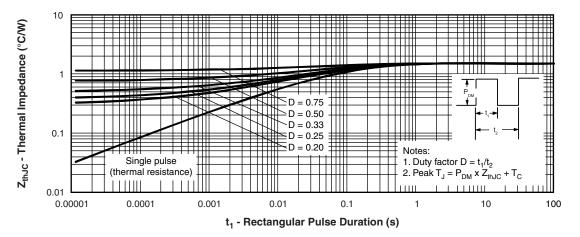
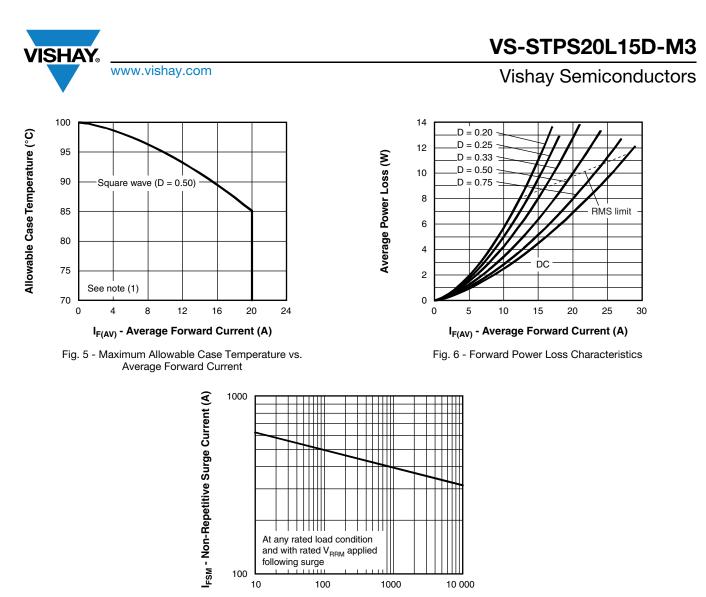
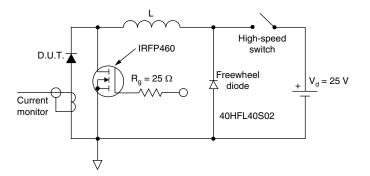


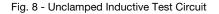
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current





Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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4

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Device

ORDERING INFORMATION TABLE

code	VS-	STPS	20	L	15	D	-M3
	1	2	3	4	5	6	7
	1 -	Vish	ay Sem	iconduc	tors pro	duct	
	2 -	Sch	ottky ST	PS seri	es		
	3 -	Curi	rent ratii	ng (20 =	20 A)		
	4 -	L =	Low vol	tage dro	р		
	5 -	Volt	age ratii	ng (15 =	15 V)		
	6 -	D =	Essenti	al part n	umber		
	7 -	. Env	ironmer	ntal digit			
	Ŀ	M3	- haloc	ion froo	DALC	complian	t and t

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION							
VS-STPS20L15D-M3	50	Antistatic plastic tubes					

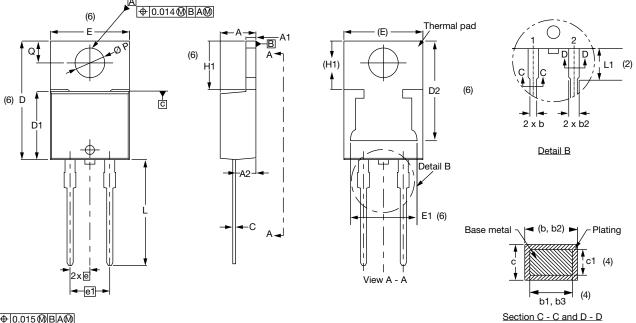
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?95305			



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TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIMETERS		INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
e	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC[®] outline TO-220AC

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

(4) Dimension b1, b3, and c1 apply to base metal only

- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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1

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 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994 $\,$

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Controlling dimensions: inches



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